# NSN 5961-01-210-1183

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Inclosure Material:

Metal

**Overall Length:** 

0.260 inches

# Terminal Length:

0.500 inches

# **Overall Diameter:**

0.370 inches

### **Internal Configuration:**

Field effect-dual gate

### **Mounting Method:**

Terminal

### **Terminal Circle Diameter:**

0.100 inches

#### Features Provided:

# Hermetically sealed case

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

60.0 drain to source voltage and 60.0 drain to gate voltage

# **Current Rating Per Characteristic:**

1.10 amperes drain current

# Power Rating Per Characteristic:

6.25 watts total power dissipation

### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

# **Terminal Type And Quantity:**

3 uninsulated wire lead

Shelf Life:

N/a

### Unit Of Measure:

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# Demilitarization:

No

### Fiig:

A110a0